Absolute Maximum Ratings

 $T_i = 25 \, ^{\circ}C$

 $T_i = 175$ °C

 $T_i = 175 \,^{\circ}C$

 λ_{paste} =0.8 W/(mK)

 λ_{paste} =2.5 W/(mK)

 $T_s = 25 \, ^{\circ}C$

 $T_s = 70 \, ^{\circ}C$

 $T_s = 25 \, ^{\circ}C$

T_s = 70 °C

Symbol | Conditions

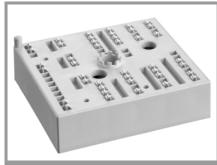
Inverter - IGBT

 V_{CES}

 I_{C}

 I_{Cnom}

 I_{CRM}



MiniSKiiP® 2

Sixpack

SKiiP 24AC12T4V1

Features*

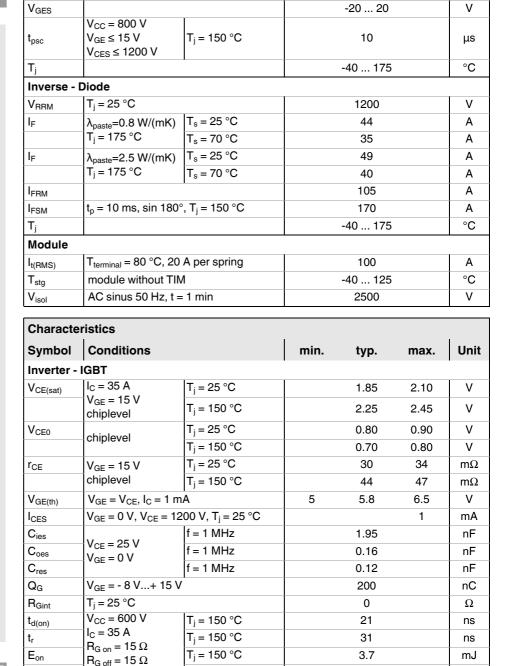
- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Typical Applications

- · Inverter up to 22 kVA
- · Typical motor power 11 kW

Remarks

- V_{CEsat}, V_F = chip level value
- Case temp. limited to T_C = 125°C max. (for baseplateless modules T_C = T_S)
- product rel. results valid for T_j ≤150 (recomm. T_{op} = -40 ... +150°C)



Values

1200

52

43

59

48

35

105

310

63

3

0.85

0.69

ns

ns

mJ K/W

K/W

Unit

٧

Α

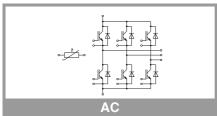
Α

Α

Α

Α

Α



 $di/dt_{off} = 460 \text{ A/}\mu\text{s}$

 $V_{GE} = +15/-15 \text{ V}$

 $t_{d(off)}$

 t_{f}

Eoff

 $R_{th(j\text{-}s)}$

 $R_{th(j-s)}$

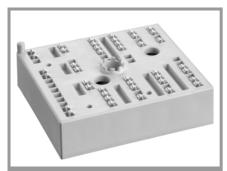
 $di/dt_{on} = 1300 \text{ A/}\mu\text{s} | T_j = 150 ^{\circ}\text{C}$

per IGBT, λ_{paste}=0.8 W/(mK)

per IGBT, λ_{paste}=2.5 W/(mK)

T_i = 150 °C

T_i = 150 °C



MiniSKiiP® 2

Sixpack

SKiiP 24AC12T4V1

Features*

- Trench 4 IGBTs
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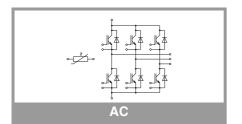
Typical Applications

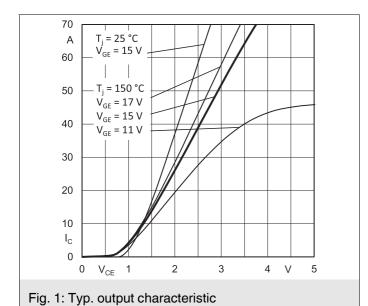
- Inverter up to 22 kVA
- Typical motor power 11 kW

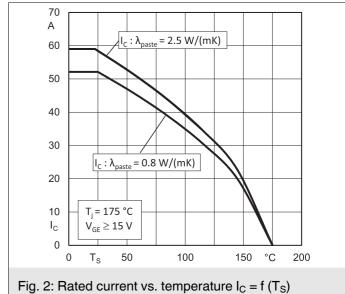
Remarks

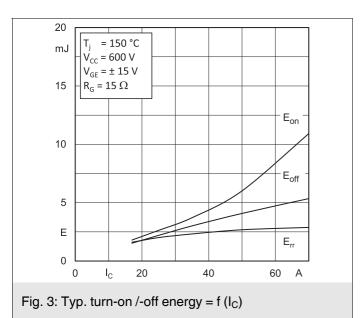
- V_{CEsat}, V_F = chip level value
- Case temp. limited to $T_C = 125$ °C max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \le 150$ (recomm. $T_{op} = -40 \dots +150$ °C)

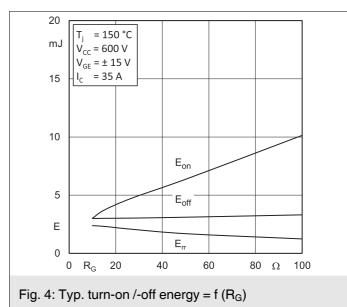
| Characte | eristics | | | | | | |
|----------------------|---|-------------------------|-----------|------|------|-----------|--|
| Symbol | Conditions | | min. | typ. | max. | Unit | |
| Inverse - | Diode | · | | | | • | |
| $V_F = V_{EC}$ | $I_F = 35 \text{ A}$ | T _j = 25 °C | | 2.30 | 2.62 | V | |
| | V _{GE} = 0 V chiplevel | T _j = 150 °C | | 2.29 | 2.62 | V | |
| V _{F0} | chiplevel | T _j = 25 °C | | 1.30 | 1.50 | V | |
| | Chipievei | T _j = 150 °C | | 0.90 | 1.10 | V | |
| r _F | chiplevel | T _j = 25 °C | | 29 | 32 | $m\Omega$ | |
| | Chipievei | T _j = 150 °C | | 40 | 43 | mΩ | |
| I _{RRM} | di/dt _{off} = 1400 A/μs V _{GE} = +15/-15 V | T _j = 150 °C | | 38 | | Α | |
| Q _{rr} | | T _j = 150 °C | | 6.2 | | μC | |
| E _{rr} | | T _j = 150 °C | | 2.3 | | mJ | |
| R _{th(j-s)} | per Diode, $\lambda_{paste}=0$. | | 1.2 | | K/W | | |
| R _{th(j-s)} | per Diode, λ _{paste} =2. | | 1 | | K/W | | |
| Module | | | | | | | |
| L _{CE} | | | | - | | nΗ | |
| Ms | to heat sink | 2 | | 2.5 | Nm | | |
| W | | | | 55 | | g | |
| Temperat | ture Sensor | | | | | | |
| R ₁₀₀ | T _r =100°C (R ₂₅ =100 | | 1670 ± 3% | | Ω | | |
| R _(T) | $R_{(T)}=1000\Omega[1+A(T-25^{\circ}C)+B(T-25^{\circ}C)^{2}]$, A = 7.635*10 ^{-3°} C ⁻¹ , B = 1.731*10 ^{-5°} C ⁻² | | | | | | |

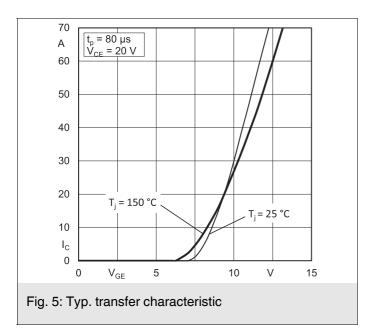


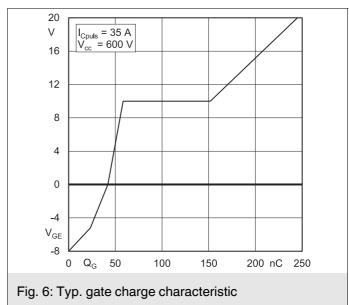


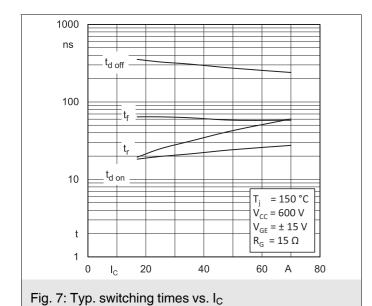


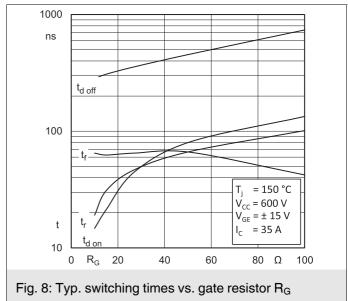


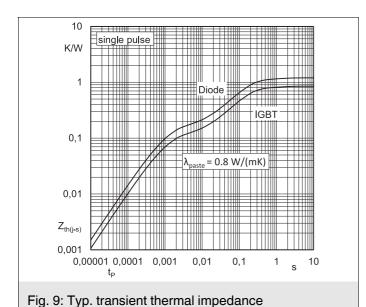


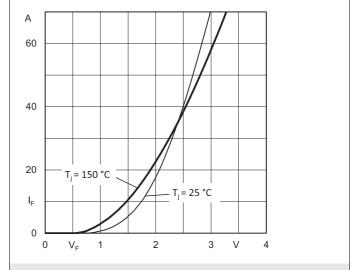












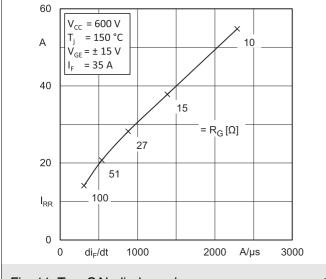


Fig. 10: Typ. CAL diode forward characteristic

27

51

 $I_F[A] =$

25

17

15

 \pm 35

2500

[A/µs]

10

70

V_{CC} = 600 V

 $V_{GE} = \pm 15 \text{ V}$

100

 $= R_G[\Omega]$

500

di_F/dt

= 150 °C

[µC]

8

6

2

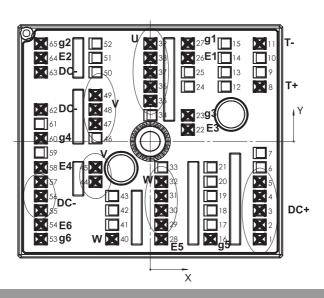
 Q_{rr} 0



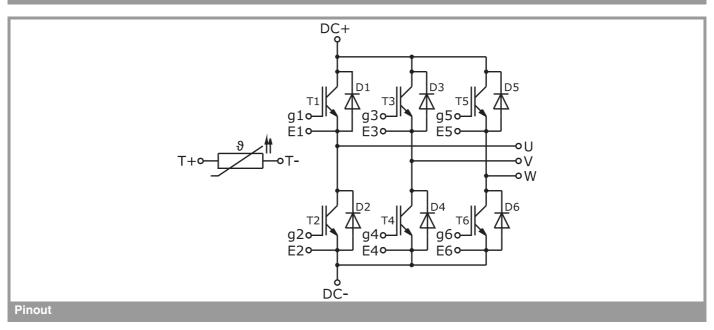
Fig. 11: Typ. CAL diode peak reverse recovery current

| Pin out | | | | | | | | | | | |
|---------|-------|--------|----------|-----|--------|--------|----------|-----|--------|--------|----------|
| Pin | X | Υ | Function | Pin | X | Υ | Function | Pin | X | Υ | Function |
| 1 | 24,38 | -21,80 | DC+ | 23 | 8,38 | 5,80 | g3 | 45 | -12,23 | -5,80 | V |
| 2 | 24,38 | -18,60 | DC+ | 24 | 8,38 | 12,20 | | 46 | -12,23 | 0,70 | |
| 3 | 24,38 | -15,40 | DC+ | 25 | 8,38 | 15,40 | | 47 | -12,23 | 3,90 | V |
| 4 | 24,38 | -12,20 | DC+ | 26 | 8,38 | 18,60 | E1 | 48 | -12,23 | | V |
| 5 | 24,38 | -9,00 | DC+ | 27 | 8,38 | 21,80 | g1 | 49 | -12,23 | 10,30 | V |
| 6 | 24,38 | -5,80 | | 28 | 2,46 | -21,80 | E5 | 50 | -12,23 | 15,40 | |
| 7 | 24,38 | -2,60 | | 29 | 2,46 | -18,60 | W | 51 | -12,23 | 18,60 | |
| 8 | 24,38 | 12,20 | T+ | 30 | 2,46 | -15,40 | W | 52 | -12,23 | | |
| 9 | 24,38 | 15,40 | | 31 | 2,46 | -12,20 | W | 53 | -24,38 | -21,80 | g6 |
| 10 | 24,38 | 18,60 | | 32 | 2,46 | -9,00 | W | 54 | -24,38 | -18,60 | E6 |
| 11 | 24,38 | 21,80 | T- | 33 | 2,46 | -5,80 | | 55 | -24,38 | -15,40 | DC- |
| 12 | 16,58 | 12,20 | | 34 | 0,03 | 5,80 | | 56 | -24,38 | -12,20 | DC- |
| 13 | 16,58 | 15,40 | | 35 | 0,03 | 9,00 | U | 57 | -24,38 | -9,00 | DC- |
| 14 | 16,58 | 18,60 | | 36 | 0,03 | 12,20 | U | 58 | -24,38 | -5,80 | E4 |
| 15 | 16,58 | 21,80 | | 37 | 0,03 | 15,40 | U | 59 | -24,38 | -2,50 | |
| 16 | 13,42 | -21,80 | g5 | 38 | 0,03 | 18,60 | U | 60 | -24,38 | 0,70 | g4 |
| 17 | 13,42 | -18,60 | | 39 | 0,03 | 21,80 | U | 61 | -24,38 | 3,90 | |
| 18 | 13,42 | -15,40 | | 40 | -8,51 | -21,80 | W | 62 | -24,38 | 7,10 | DC- |
| 19 | 13,42 | -12,20 | | 41 | -8,51 | -18,60 | | 63 | -24,38 | 15,40 | DC- |
| 20 | 13,42 | -9,00 | | 42 | -8,51 | -15,40 | | 64 | -24,38 | 18,60 | E2 |
| 21 | 13,42 | -5,80 | | 43 | -8,51 | -12,20 | | 65 | -24,38 | 21,80 | g2 |
| 22 | 8,38 | 2,60 | E3 | 44 | -12,23 | -9,00 | V | | | | |

all values in mm



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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